

Spezifikationen	
Artikelnummer	MJD32CTM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PNP 100V 3A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	3051 pcs Stock
Spannung - Kollektor-Emitter-Durchbruch (max)	100V
VCE Sättigung (Max) @ Ib, Ic	1.2V @ 375mA, 3A
Transistor-Typ	PNP
Supplier Device-Gehäuse	D-Pak
Serie	-
Leistung - max	1.56W
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Andere Namen	MJD32CTM-ND
Betriebstemperatur	150°C (TJ)
Befestigungsart	Surface Mount
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Hersteller Standard Vorlaufzeit	13 Weeks
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Frequenz - Übergang	3MHz
detaillierte Beschreibung	Bipolar (BJT) Transistor PNP 100V 3A 3MHz 1.56W
DC Stromgewinn (HFE) (Min) @ Ic, VCE	10 @ 3A, 4V
Strom - Collector Cutoff (Max)	50µA
Strom - Kollektor (Ic) (max)	3A
Basisteilenummer	MJD32

sein: MJD32CTF IC FAIRCHILD FAIRCHILD 252	MJD32CTF Fairchild/ON Semiconductor TRANS PNP 100V 3A DPAK	MJD32CUQ-13 Diodes Incorporated PWR MID PERF TRANSISTOR TO252	MJD32RL TO-252 MJD32RL TO-252
MJD32CTF_NBDD002 AMI Semiconductor / ON Semiconductor TRANS PNP 100V 3A DPAK	MJD32CTF AMI Semiconductor / ON Semiconductor TRANS PNP 100V 3A DPAK	MJD32RL MOS ON ON TO-252	MJD32CTF_NBDD002 Fairchild/ON Semiconductor TRANS PNP 100V 3A DPAK

Schlüsselwort				
MJD32CTM Semiconductor / ON Semiconductor	MJD32CTM Datenblatt	MJD32CTM-Datenblätter	MJD32CTM PDF	AMI Semiconductor / ON Semiconductor MJD32CTM
MJD32CTM Electronic	MJD32CTM-Komponenten	MJD32CTM-Verteiler	MJD32CTM-Bild	MJD32CTM-Teil
MJD32CTM Preis	MJD32CTM Hersteller	MJD32CTM Bild	MJD32CTM Aktie	MJD32CTM Inventar
MJD32CTM Neu	MJD32CTM Original	MJD32CTM garantiert	MJD32CTM RFQ	MJD32CTM Online bestellen